

TL082 TL082A TL082B

General purpose JFET dual operational amplifiers

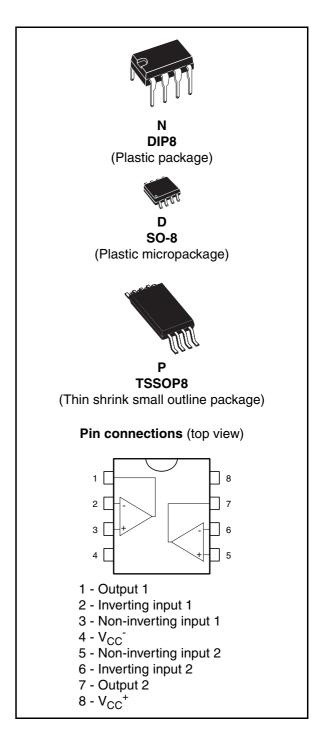
Features

- Wide common-mode (up to V_{CC}⁺) and differential voltage range
- Low input bias and offset current
- Output short-circuit protection
- High input impedance JFET input stage
- Internal frequency compensation
- Latch up free operation
- High slew rate: 16 V/µs (typical)

Description

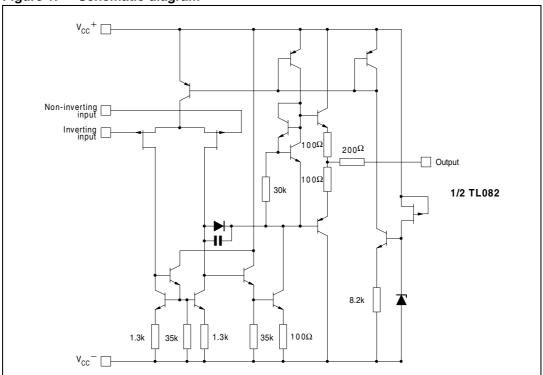
The TL082, TL082A and TL082B are high speed JFET input dual operational amplifiers incorporating well matched, high voltage JFET and bipolar transistors in a monolithic integrated circuit.

The devices feature high slew rates, low input bias and offset current, and low offset voltage temperature coefficient.



1 Schematic diagram

Figure 1. Schematic diagram



2 Absolute maximum ratings and operating conditions

Table 1. Absolute maximum ratings

Symbol	Parameter	TL082I, AI, BI	TL082C, AC, BC	Unit
V _{CC}	Supply voltage ⁽¹⁾	±	18	V
V _{in}	Input voltage (2)	±	15	V
V _{id}	Differential input voltage (3)	±:	30	V
P _{tot}	Power dissipation	68	80	mW
R _{thja}	Thermal resistance junction to ambient ⁽⁴⁾ SO-8 DIP8 TSSOP8		25 35 20	°C/W
R _{thjc}	Thermal resistance junction to case SO-8 DIP8 TSSOP8	40 41 37		°C/W
	Output short-circuit duration (5)	Infi	nite	
T _{stg}	Storage temperature range	-65 to +150		°C
	HBM: human body model ⁽⁶⁾	1		kV
ESD	MM: machine model ⁽⁷⁾	20	V	
	CDM: charged device model ⁽⁸⁾	15	1500	

All voltage values, except differential voltage, are with respect to the zero reference level (ground) of the supply voltages where the zero reference level is the midpoint between V_{CC}⁺ and V_{CC}⁻.

- 3. Differential voltages are the non-inverting input terminal with respect to the inverting input terminal.
- Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous shortcircuit on all amplifiers.
- The output may be shorted to ground or to either supply. Temperature and/or supply voltages must be limited to ensure that the dissipation rating is not exceeded
- 6. Human body model: 100 pF discharged through a 1.5 $k\Omega$ resistor between two pins of the device, done for all couples of pin combinations with other pins floating.
- 7. Machine model: a 200 pF cap is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5 Ω), done for all couples of pin combinations with other pins floating.
- Charged device model: all pins plus package are charged together to the specified voltage and then discharged directly to the ground.

Table 2. Operating conditions

Symbol	Parameter	TL082I, AI, BI	TL082C, AC, BC	Unit
V _{CC}	Supply voltage	6 to	36	V
T _{oper}	Operating free-air temperature range	-40 to +105	0 to +70	°C

The magnitude of the input voltage must never exceed the magnitude of the supply voltage or 15 volts, whichever is less.

3 Electrical characteristics

Table 3. $V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified)

Symbol	Parameter		TL082I,AC,AI,BC, BI			TL082C		
-		Min.	Тур.	Max.	Min.	Тур.	Max.	
V _{io}	Input offset voltage ($R_s = 50\Omega$) $T_{amb} = +25^{\circ}C \qquad TL082$ $TL082A$ $TL082B$ $T_{min} \leq T_{amb} \leq T_{max}TL082$ $TL082A$ $TL082B$		3 3 1	10 6 3 13 7 5		3	10	mV
DV _{io}	Input offset voltage drift		10			10		μV/°C
I _{io}	Input offset current ⁽¹⁾ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		5	100 4		5	100 10	pA nA
l _{ib}	Input bias current $T_{amb} = +25^{\circ}C$ $T_{min} \leq T_{amb} \leq T_{max}$		20	200 20		20	400 20	pA nA
A _{vd}	Large signal voltage gain $(R_L = 2k\Omega \ V_o = \pm 10V)$ $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		200		25 15	200		V/mV
SVR	Supply voltage rejection ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		86		70 70	86		dB
I _{CC}	Supply current, no load $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		1.4	2.5 2.5		1.4	2.5 2.5	mA
V _{icm}	Input common mode voltage range	±11	+15 -12		±11	+15 -12		V
CMR	Common mode rejection ratio ($R_S = 50\Omega$) $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		86		70 70	86		dB
I _{os}	Output short-circuit current $T_{amb} = +25^{\circ}C$ $T_{min} \le T_{amb} \le T_{max}$		40	60 60	10 10	40	60 60	mA
$\pm V_{opp}$	$ \begin{array}{ll} \text{Output voltage swing} \\ T_{amb} = +25^{\circ}\text{C} & R_{L} = 2k\Omega \\ & R_{L} = 10k\Omega \\ T_{min} \leq T_{amb} \leq T_{max} & R_{L} = 2k\Omega \\ & R_{L} = 10k\Omega \end{array} $	10 12 10 12	12 13.5		10 12 10 12	12 13.5		V
SR	Slew rate $V_{in} = 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, unity gain	8	16		8	16		V/µs

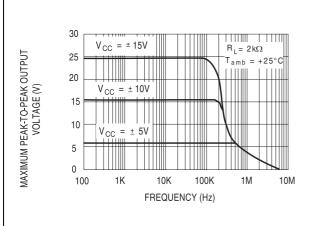
Table 3. $V_{CC} = \pm 15V$, $T_{amb} = +25^{\circ}C$ (unless otherwise specified) (continued)

Symbol	Parameter		TL082I,AC,AI,BC, BI			TL082C		
			Тур.	Max.	Min.	Тур.	Max.	
t _r	Rise time $V_{in} = 20$ mV, $R_L = 2$ k Ω , $C_L = 100$ pF, unity gain		0.1			0.1		μs
K _{ov}	Overshoot $V_{in} = 20$ mV, $R_L = 2$ k Ω , $C_L = 100$ pF, unity gain		10			10		%
GBP	Gain bandwidth product V_{in} = 10mV, R_L = 2k Ω C_L = 100pF, F= 100kHz		4		2.5	4		MHz
R _i	Input resistance		10 ¹²			10 ¹²		Ω
THD	Total harmonic distortion F=1kHz, $R_L = 2k\Omega C_L$ =100pF, A_v =20dB, V_o =2 V_{pp}		0.01			0.01		%
e _n	Equivalent input noise voltage $R_S = 100\Omega$, $F = 1$ kHz		15			15		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
Øm	Phase margin		45			45		degrees
V ₀₁ /V ₀₂	Channel separation $A_V = 100$		120			120		dB

^{1.} The input bias currents are junction leakage currents which approximately double for every 10° C increase in the junction temperature.

Figure 2. Maximum peak-to-peak output voltage versus frequency

Figure 3. Maximum peak-to-peak output voltage versus frequency



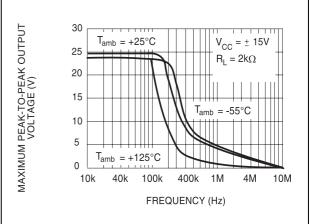
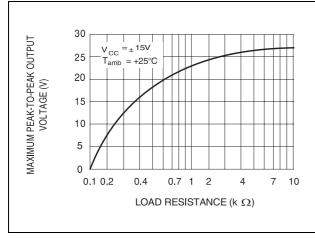


Figure 4. Maximum peak-to-peak output voltage versus load resistance

Figure 5. Maximum peak-to-peak output voltage versus frequency



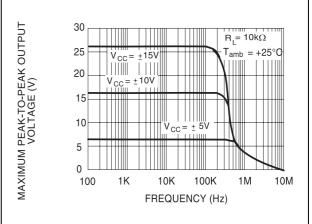
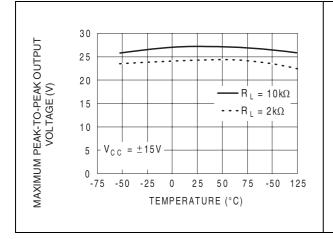


Figure 6. Maximum peak-to-peak output voltage versus free air temperature

Figure 7. Maximum peak-to-peak output voltage versus supply voltage



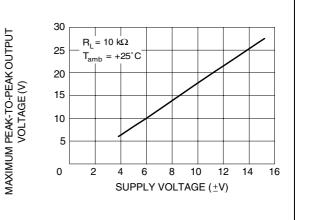
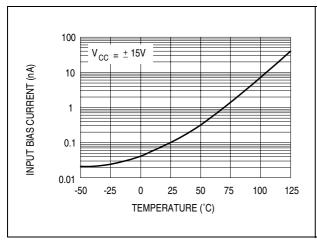


Figure 8. Input bias current versus free air temperature

Figure 9. Large signal differential voltage amplification and phase shift versus frequency



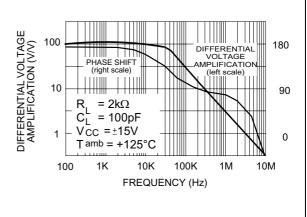
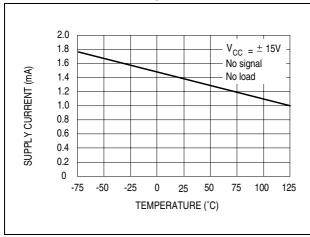


Figure 10. Supply current per amplifier versus Figure 11. Large signal differential voltage free air temperature amplification versus free air temp.



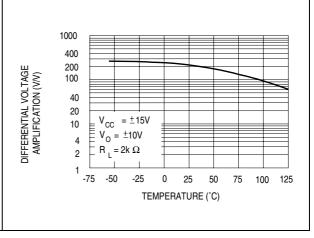
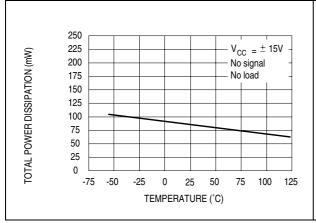


Figure 12. Total power dissipation versus free Figure 13. Supply current per amplifier versus air temperature supply voltage



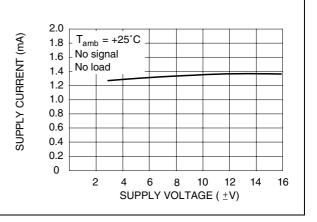


Figure 14. Common mode rejection ratio versus free air temperature

Figure 15. Output voltage versus elapsed time

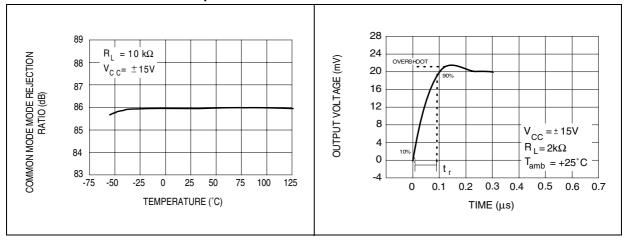


Figure 16. Voltage follower large signal pulse Figure 17. Equivalent input noise voltage response versus frequency

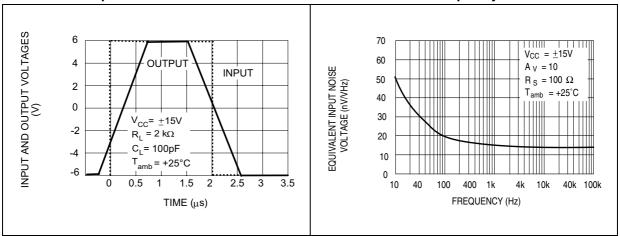
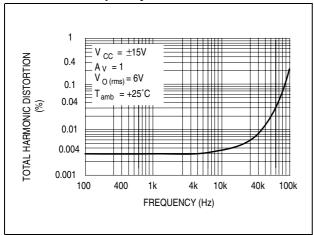


Figure 18. Total harmonic distortion versus frequency



4 Parameter measurement information

Figure 19. Voltage follower

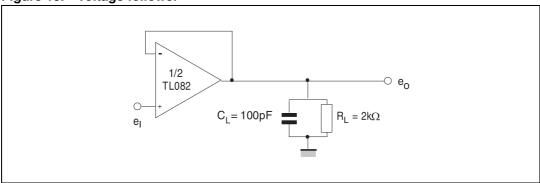
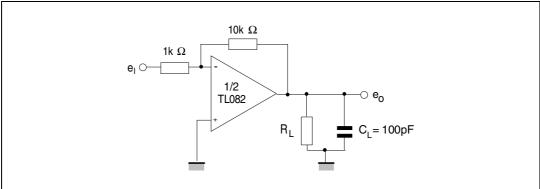
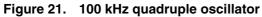
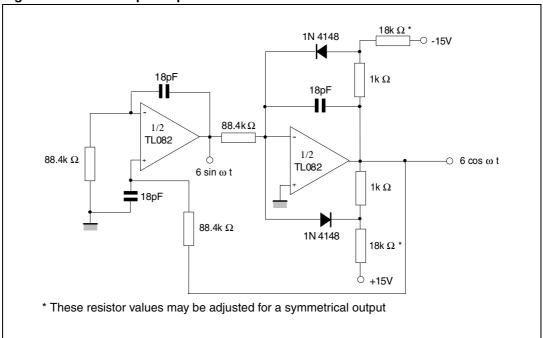


Figure 20. Gain-of-10 inverting amplifier



5 Typical applications





6 Package information

In order to meet environmental requirements, STMicroelectronics offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an STMicroelectronics trademark. ECOPACK specifications are available at: www.st.com.

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6.1 DIP8 package information

Figure 22. DIP8 package mechanical drawing

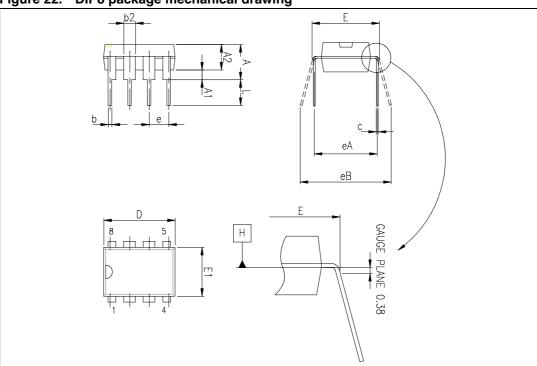


Table 4. DIP8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
С	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
е		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

6.2 **SO-8 package information**

Figure 23. SO-8 package mechanical drawing

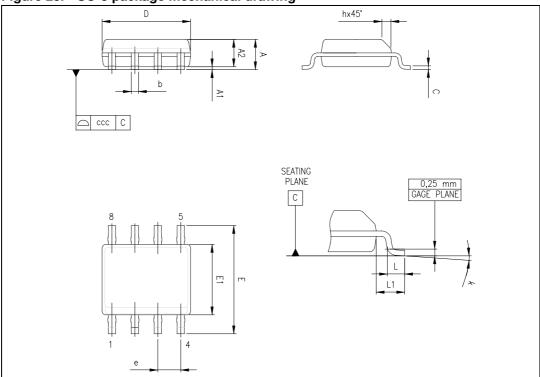


Table 5. SO-8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
А			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
С	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
E	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
е		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	1°		8°	1°		8°
ccc			0.10			0.004

6.3 TSSOP8 package information

Figure 24. TSSOP8 package mechanical drawing

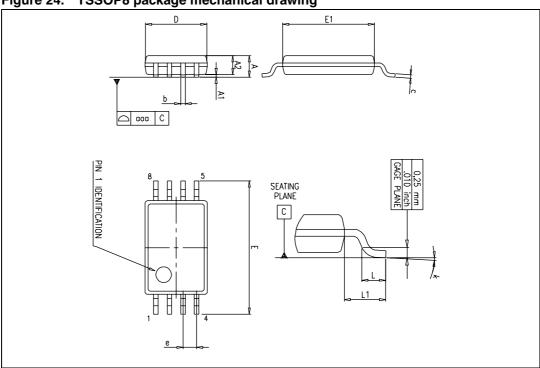


Table 6. TSSOP8 package mechanical data

			Dimer	nsions		
Ref.		Millimeters			Inches	
	Min.	Тур.	Max.	Min.	Тур.	Max.
Α			1.2			0.047
A1	0.05		0.15	0.002		0.006
A2	0.80	1.00	1.05	0.031	0.039	0.041
b	0.19		0.30	0.007		0.012
С	0.09		0.20	0.004		0.008
D	2.90	3.00	3.10	0.114	0.118	0.122
E	6.20	6.40	6.60	0.244	0.252	0.260
E1	4.30	4.40	4.50	0.169	0.173	0.177
е		0.65			0.0256	
k	0°		8°	0°		8°
L	0.45	0.60	0.75	0.018	0.024	0.030
L1		1			0.039	
aaa		0.1			0.004	

7 Ordering information

Table 7. Order codes

Order code	Temperature range	Package	Packing	Marking
TL082IN		DIP8	Tube	TL082IN
TL082ID TL082IDT		SO-8	Tube or tape & reel	0821
TL082IPT		TSSOP8	Tape & reel	
TL082AIN		DIP8	Tube	TL082AIN
TL082AID TL082AIDT	-40°C, +105°C	SO-8	Tube or tape & reel	082AI
TL082AIPT		TSSOP8	Tape & reel	
TL082BIN		DIP8	Tube	TL082BIN
TL082BID TL082BIDT		SO-8	Tube or tape & reel	082BI
TL082BIPT		TSSOP8	Tape & reel	
TL082CN		DIP8	Tube	TL082CN
TL082CD TL082CDT		SO-8	Tube or tape & reel	082C
TL082CPT		TSSOP8	Tape & reel	
TL082ACN		DIP8	Tube	TL082ACN
TL082ACD TL082ACDT	0°C, +70°C	SO-8	Tube or tape & reel	082AC
TL082ACPT		TSSOP8	Tape & reel	
TL082BCN		DIP8	Tube	TL082BCN
TL082BCD TL082BCDT		SO-8	Tube or tape & reel	082BC
TL082BCPT		TSSOP8	Tape & reel	
TL082IYDT ⁽¹⁾		222		082IY
TL082AIYDT ⁽¹⁾	-40°C, +105°C	SO8 (automotive grade)	Tube or tape & reel	82AIY
TL082BIYDT ⁽¹⁾		(actornotive grade)		82BIY

Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

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Revision history TL082 TL082A TL082B

8 Revision history

Table 8. Document revision history

Date	Revision	Changes
02-Apr-2001	1	Initial release.
2002-2003	2-7	Internal revisions.
30-Apr-2004	8	Format update.
06-Mar-2007	9	Added ESD information in <i>Table 1 on page 3</i> . Expanded order codes table and added automotive grade order codes. See <i>Table 7 on page 15</i> . Added <i>Table 2: Operating conditions on page 3</i> . Updated package information to make it compliant with the latest JEDEC standards.
17-Jun-2008	10	Removed information concerning military temperature range (TL082M*, TL082AM*, TL082BM*).

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